

# 1N5807US/1N5809US/1N5811US Superfast Recovery Diodes Surface Mount (US)

# **POWER DISCRETES**

## Description

Quick reference data

V<sub>R</sub> 50 -150 V

 $I_{\rm F}$  1N5807US to 1N5811US = 6A

 $t_{rr}$  1N5807US to 1N5811US = 30nS

 $I_{R}^{"}$  1N5807US to 1N5811US = 5 $\mu$ A

#### **Features**

- ◆ Very low reverse recovery time
- ◆ Hermetically sealed non-cavity construction
- ◆ Soft, non-snap, off recovery characteristics
- Very low forward voltage drop

These products are qualified to MIL-PRF-19500/477 and are preferred parts as listed in MIL-HDBK-5961. They can be supplied fully released as JANTX , JANTXV and JANS versions.

### **Electrical Specifications**

Electrical specifications @  $T_A = 25$ °C unless otherwise specified.

	Symbol	1N5807US	1N5809US	1N5811US	Units
Working Reverse Voltage	$V_{_{\mathrm{RWM}}}$	50	100	150	V
Repetitive Reverse Voltage	$V_{RRM}$	50	100	150	V
Average Forward Current (@ 75°C lead length = 0.375')	I <sub>F(AV)</sub>	6.0		А	
Repetitive Surge Current (@ 55°C in free air lead length = 0.375')	I <sub>FRM</sub>	25		А	
Non-Repetitive Surge Current (tp = 8.3mS @ Vr & T <sub>JMAX</sub> )	I <sub>FSM</sub>	125		А	
Storage Temperature Range	T <sub>STG</sub>	-65 to +175		°C	
Average Forward Current Max (pcb mounted: $T_A = 55^{\circ}C$ ) Sine wave Square wave (d = 0.5)	I <sub>F(AV)</sub> I <sub>F(AV)</sub>	1.7 1.8		A	
Pt for fusing (t = 8.3mS) max	l²t	32		A <sup>2</sup> S	
Forward Voltage Drop max @ T <sub>J</sub> = 25°C	V <sub>F</sub>	0.875 @ 4A		V	
Reverse Current max @ $V_{WRM}$ , $T_J = 25^{\circ}C$ @ $V_{WRM}$ , $T_J = 100^{\circ}C$	l R I <sub>R</sub>	5.0 150		μА	
Reverse Recovery Time max (1.0A $I_F$ to 1.0A $I_{RM}$ recover to 0.25A $I_{RM(REC)}$ )	trr		30		nS
Junction Capacitance typ  @ V <sub>R</sub> = 5V f = 1MHz	C <sub>J</sub>	60		pF	
Thermal Resistance to end cap	R <sub>eJEC</sub>		6.5		°C/W



# 1N5807US/1N5809US/1N5811US

#### POWER DISCRETES

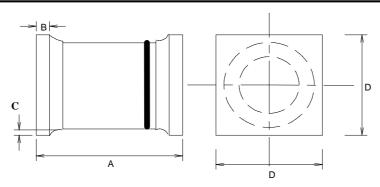
Ordering information				
Part Number	Description			
1N5807US, 1N5809US,	Surface Mount <sup>(1)</sup>			

#### Note:

(1) Available in trays and tape and reel packaging. Please consult factory for quantities.

# **Outline Drawing**

1N5811US



\*Cathode is denoted by a black band on a white body.

	Dimensions in Inches 1N5807US - 1N5811US				
	MIN	MAX			
Α	0.2	0.225			
В	0.019	0.028			
С	0.003	-			
D	0.137	0.148			

# Contact Information

Semtech Corporation Power Discretes Products Division 200 Flynn Road, Camarillo, CA 93012 Phone: (805)498-2111 FAX (805)498-3804

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

# Semtech:

JANTXV1N5809US JANTX1N5809US JANTX1N5811US JANTX1N5807US JANTXV1N5807US JANTXV1N5811US